Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3	"20030151567"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/28 15:07
L2	4	("6586888"   "6747417"   "6756738"   "6777885").PN. OR ("6992647").URPN.	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/28 15:07
L4	3862	315/169.3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/28 16:16
L5	1	4 and (MISFET)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON .	2006/04/28 16:17
L6	2005	315/169.4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/28 16:17
L7	1	6 and (MISFET)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/28 16:17
L8	30	("3725899"   "4432610"   "5349366"   "5412596"   "5642213"   "5668754").PN. OR ("6072454"). URPN.	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/28 16:19
L9	1456	345/76	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/28 16:19
L10	0	9 and (MISFET)	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/28 16:19
L11	3584	345/204	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/28 16:19
L12	5	11 and (MISFET)	US-PGPUB; USPAT; USOCR	AND	ON.	2006/04/28 16:19
L13	9	("3862360"   "4532506"   "5200741").PN. OR ("5587722"). URPN.	US-PGPUB; USPAT; USOCR	AND ·	ON	2006/04/28 16:21

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L14	0	(current adj driving) near (semiconductor adj chip) near display	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/28 16:22
L15	0	(current adj driving) near (semiconductor adj chip) near display	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/28 16:22
L16	0	(current near3 driv\$3) near (semiconductor near3 chip) near (display or terminal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/28 16:23
L17	1	US "20040227499"	US-PGPUB	AND	ON	2006/04/28 16:24
L18	0	(current driving device semiconductor chip first-conductive-type first MISFET reference current source reference current flow first-conductive-type current distribution MISFET current mirror circuit first MISFET and makes the reference second-conductive-type current input MISFET current distribution MISFET current supply sections source MISFETs current mirror). CLM.	US-PGPUB	AND	ON	2006/04/28 16:27
L19	0	(current driving device semiconductor chip first-conductive-type MISFET current source reference conductive-type current distribution MISFET second-conductive-type current input MISFET current distribution MISFET current supply sections source MISFETs).CLM.	US-PGPUB	AND	ON	2006/04/28 16:28
L20	1	(current driving device semiconductor chip MISFET current source reference MISFET current input MISFET current distribution MISFET current supply sections source).CLM.	US-PGPUB	AND	ON	2006/04/28 16:29
S1	2	"6,332,661".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 18:05

S2	2812	323/315	US-PGPUB; USPAT; EPO; JPO; DERWENT;	AND	ON	2006/04/27 15:03
S3	8	S2 and MISFET	IBM_TDB US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:37
S4	1	S3 and reference adj current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:04
S5 .	2	US "20040227499"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND ·	ON	2006/04/27 15:37
S6	1	S3 and (current adj reference)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:38
S7	4	S3 and (mirror)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:38
S8	3	S7 and (semiconductor near chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:43
S10	2	S8 and (display or (display with data))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:43
S11	3	S3 and (display or (display with data))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:45
S12	1	S2 and ((driving adj circuit\$3 near display) or (current adj driver near display))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND _	ON	2006/04/27 15:50

S13	0	S12 and "200"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:47
S14	4	S3 and "200"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:47
S15	0	S3 and ("200" near meter)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:47
S16	3234	((driving adj circuit\$3 near display) or (current adj driver near display))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ÓN	2006/04/27 15:50
S17	10	S16 and (MISFET)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:50
S18	8	S17 and reference	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:50
S19	5	S18 and mirror	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 15:51
S20	1	S19 and "200"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 16:39
S21	542	327/53	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 16:40
S22	2	S21 and (MISFET)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 16:49

S23	537	327/66	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 16:49
S25	3	S23 and (MISFET)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 16:50
S26	9	("3365584"   "4825104"   "4912745"   "5004932"   "5469392").PN. OR ("5838166"). URPN.	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 16:54
S27	841	327/105	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 16:55
S28	3	S27 and (MISFET)	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 16:56
S29	68	S27 and (current adj mirror)	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 16:56
S30	189	S27 and (IC or (semiconductor adj chip))	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 16:57
S31	26	S29 and (IC or (semiconductor adj chip))	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 17:46
S32	2657	327/538	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 17:46
S33	6	S32 and (MISFET)	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 17:48
S34	748	327/539	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:49
S35	1	S34 and (MISFET)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:50

S36	1754	327/540	US-PGPUB;	AND	ON	2006/04/27 17-50
536	1754	327/540	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:50
S37	0	S36 and (MISFET)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:51
S38	1685	327/541	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:51
S39	5	S38 and (MISFET)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:53
S40	308	327/542	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:53
S41	0	S40 and (MISFET)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:53
S42	1777	327/543	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:53
S43	3	S42 and MISFET	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 17:54
S44	15	("4195356"   "5199000").PN. OR ("5392243").URPN.	US-PGPUB; USPAT; USOCR	AND	ON	2006/04/27 17:55

S45	3	"20030151567"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/28 16:16
S46	3	"20030151567"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 18:08
S47	2	"20030122808"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/04/27 18:08